TOSHIBA Field Effect Transistor Silicon P-Channel MOS Type (U-MOSVI)

# **TPCC8105**

### Lithium Ion Battery Applications Power Management Switch Applications

- Small footprint due to a small and thin package
- Low drain-source ON-resistance:

 $R_{DS}$  (ON) = 6.0 m $\Omega$  (typ.)( $V_{GS}$  = -10 V)

- Low leakage current:  $I_{\rm DSS}$  = –10  $\mu A$  (max) (V\_{\rm DS} = –30 V)
- Enhancement mode:  $V_{th}$  = –0.8 to –2.0 V (V\_{DS} = –10 V,  $I_{D}$  = –0.5 mA)

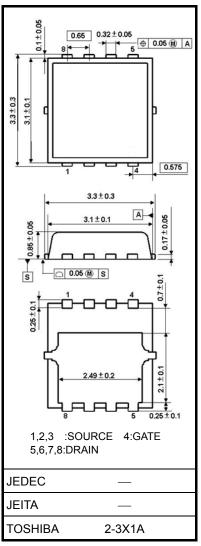
### Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Characte	eristic	Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	-30	V	
Drain-gate voltage (F	R <sub>GS</sub> = 20 kΩ)	V <sub>DGR</sub>	-30	V	
Gate-source voltage		V <sub>GSS</sub>	-25/+20	V	
Drain ourrant	DC (Note 1)	ID	-23	A	
Drain current	Pulsed (Note 1)	I <sub>DP</sub>	-69		
Drain power dissipati	on $(T_{c} = 25^{\circ}C)$	PD	30	W	
Drain power dissipati	on (t = 10 s)	P <sub>D</sub>	1.9	W	
	(Note 2a)				
Drain power dissipati	on (t = 10 s)	PD	0.7	W	
	(Note 2b)				
Single-pulse avalanc	he energy	EAS	138	mJ	
	(Note 3)	LA2	100	mo	
Avalanche current		I <sub>AR</sub>	-23	А	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature	range	T <sub>stg</sub>	–55 to 150	°C	

Note: For Notes 1 to 4, refer to the next page.

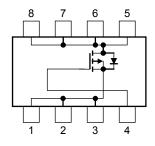
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.02 g (typ.)

### **Circuit Configuration**



Start of commercial production 2009-11

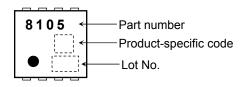
Unit: mm

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## **Thermal Characteristics**

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case $(T_{\text{C}}=25^{\circ}\text{C})$	R <sub>th(ch-c)</sub>	4.16	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th(ch-a)</sub>	65.7	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th(ch-a)</sub>	178	°C/W

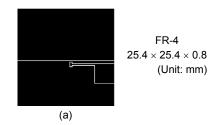
# Marking

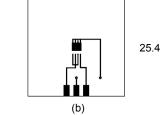


Note 1: Ensure that the channel temperature does not exceed  $150^{\circ}C$ .

#### Note 2

a: Device mounted on a glass-epoxy board (a)





Note 2b: Device mounted on a glass-epoxy board (b)

FR-4 25.4 × 25.4 × 0.8 (Unit: mm)

Note 3:  $V_{DD} = -24 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$  (initial), L = 200  $\mu$ H, R<sub>G</sub> = 1  $\Omega$ , I<sub>AR</sub> = -23 A

Electrical Characteristics ( $T_a = 25^{\circ}C$ )

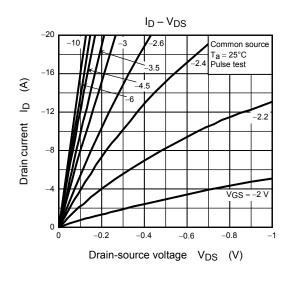
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cui	rent	I <sub>GSS</sub>	$V_{GS}=\pm 20~V,~V_{DS}=0~V$	_		±100	nA
Drain cutoff curre	ent	I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	—	-10	μA
		V <sub>(BR)DSS</sub>	$I_{D} = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30		_	v
Drain-source bre	akdown voltage	V <sub>(BR)DSX</sub>	$I_D = -10 \text{ mA}, V_{GS} = 10 \text{ V} (\text{Note 4})$	-21		_	
Gate threshold ve	oltage	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -0.5 \text{ mA}$	-0.8		V	
			$V_{GS} = -4.5V, I_D = -11.5 A$		8	10.4	mΩ
Drain-source on-resistance		R <sub>DS(ON)</sub>	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -11.5 \text{ A}$		6	7.8	
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		3240		pF
Reverse transfer capacitance		C <sub>rss</sub>			520		
Output capacitance		C <sub>oss</sub>			580		
Switching time	Rise time	tr	$V_{GS} = -11.5 \text{ A}$ $V_{GS} = -10 \text{ V}$ $G \approx 0 \text{ V}_{OUT}$ $G \approx 0 \text{ V}_{OU}$ $G \approx 0 \text{ V}_{OUT}$ $G \approx 0 \text{ V}_{OU}$ $G \approx 0 \text$	_	8	_	- ns
	Turn-on time	t <sub>on</sub>		_	14	_	
	Fall time	t <sub>f</sub>		_	110	_	
	Turn-off time	t <sub>off</sub>	Duty $\leq$ 1%, $t_W =$ 10 $\mu s$	—	330	_	
	Fotal gate charge gate-source plus gate-drain) Qg		V <sub>DD</sub> ≈ -24 V, V <sub>GS</sub> = -10 V,		76	_	
Gate-source charge 1		Q <sub>gs1</sub>	I <sub>D</sub> = -23 A	—	7.6	—	nC
Gate-drain ("Mille	er") charge	Q <sub>gd</sub>		_	20	_	

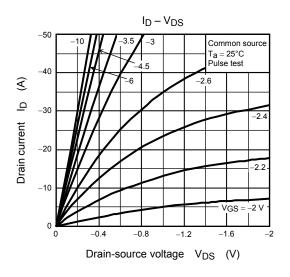
# Source-Drain Ratings and Characteristics (T<sub>a</sub> = 25°C)

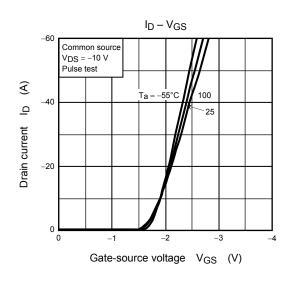
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I <sub>DRP</sub>	—		_	-69	А
Forward voltage (diode)			V <sub>DSF</sub>	$I_{DR} = -23$ A, $V_{GS} = 0$ V			1.2	V

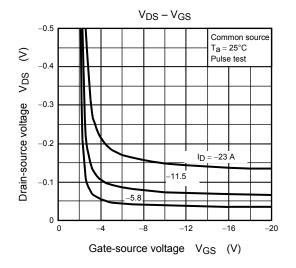
Note 4: V<sub>DSX</sub> mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.

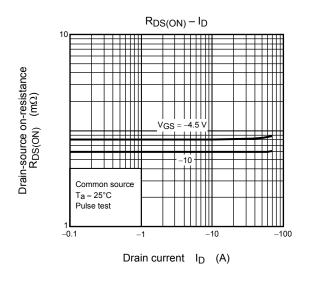
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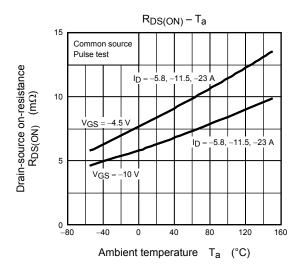


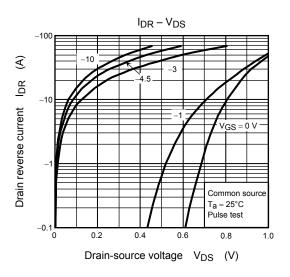


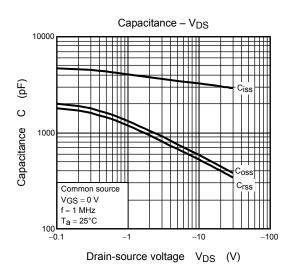


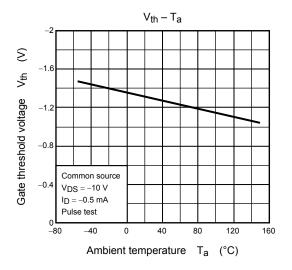


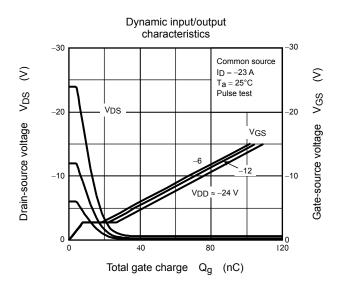
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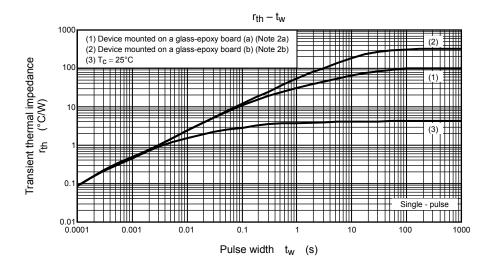


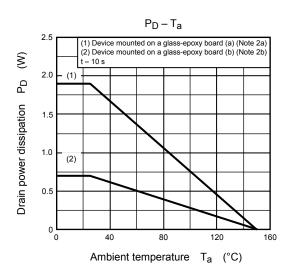


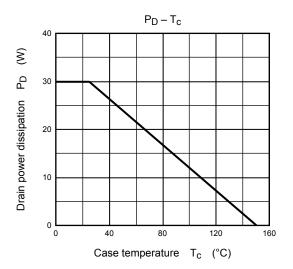


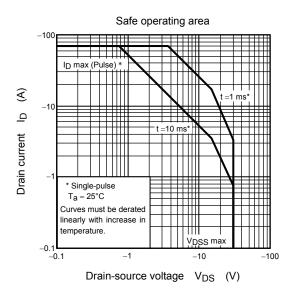












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